

Frequency domain studies of current-induced magnetization dynamics in single magnetic-layer nanopillars

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Abstract

Spin transfer torque-induced high-frequency dynamics of single thin cobalt-layer nanopillars of circular and elliptical shape have been observed directly. Two types of precessional modes can be identified as a function of magnetic field perpendicular to the layer plane, excited for negative current polarity only. They are assigned to vortex-core and transverse spin-wave excitations, which corroborate recent model predictions. The observed narrow linewidth of 4 MHz at room temperature indicates the high coherence of the magnetic excitations.

Angular momentum conservation of the electron spin is in essence the basis of spintronics. The spin angular momentum can be transferred onto the magnetization of a ferromagnet (FM), thus giving rise to so-called spin transfer torque (STT). This has been predicted theoretically and explored experimentally for magnetic nanostructures [1–9] to switch their magnetization, triggering also magnetization dynamics concomitant with emission of microwave radiation. Mainly double magnetic layer nanostructures (FM/NM/FM) of an FM layer polarizing the electron current and an STT switching layer with an intervening nonmagnetic metal (NM) spacer layer have been investigated, also regarding spin torque oscillators [9, 10]. However, recent experimental observations [11–13] and theoretical studies [14–17] suggest that even an unpolarized current passing perpendicular to a single thin FM layer can cause an STT on this FM layer. Spin filtering effects by a single FM layer contacted by NM leads creates spin accumulation of opposite sign at both interfaces. The associated torques of opposite sign may cancel each other. Asymmetric leads, however, break the symmetry of the single magnetic layer (NM/FM/NM) structure and yield a net STT on the magnetization for one current polarity only [14]. Requirement is that the spins diffuse in the NM leads along the interfaces and that the FM magnetization is nonuniform or inhomogeneous. This mechanism was not included in the Slonczewski model [1]. The direction of the torque is to align the local magnetization with the direction of the accumulated spins.

For single, extended FM layers studied by means of point contacts the predicted spin-torque induced excitations depend on competing Oersted and external magnetic fields [17]. For thick FM layers the formation of a nanodomain underneath the nanocontact obtains a more intricate experiment [11, 18]. For single FM layers laterally confined to a nanopillar, current-induced excitations of spin waves transverse to the current flow direction have been predicted [14, 16]. Assuming additionally a nonuniform magnetization normal to the layer plane for the net spin torque a lowest mode is found, which is nonuniform both parallel and perpendicular to the layer plane [15, 19]. First experimental observations of current induced resistance changes of single nanosized FM layers have been reported [12, 13]. Only by analogy to magnetic double layer structures have they been assigned to the onset of possible magnetic excitations. However, a direct experimental proof of the high frequency magnetization dynamics and identification of the excited magnetic modes is still missing.

Using frequency domain spectroscopy, we observe for a single nano-confined thin FM layer directly two types of characteristic eigenmodes triggered by a dc current perpendicular to the

layer plane. These modes are assigned to vortex-core and transverse spin-wave excitations deduced from their characteristic frequency vs current or vs field dependences. This is in contrast to previous static studies of differential-resistance dV/dI vs current I , which help only in identifying mode onsets. Asymmetries are observed with respect to current polarity for spin excitations and field polarity for microwave emission power as well as mode overtones. The small linewidth of only 4 MHz for Co at room temperature (RT) proves the high coherence due to nonlocal STT effects. Our results confirm recent qualitative predictions of current-induced spin-wave excitations in single FM layers. Moreover, they pave the way for technological applications due to relaxed constraints on magnetization uniformity and elimination of retroactions in dynamics between switching and polarizing, fixed magnetic layers [6].

The samples have been fabricated using a focused ion-beam assisted nanostencil mask technique [20]. The thin layer stack of 10 nm Cu/15 nm Co/150 nm Cu (Fig. 1(a)) is deposited by means of molecular beam epitaxy in prefabricated undercut templates on top of a Pt bottom electrode. The latter acts additionally as a spin sink ensuring the asymmetry of the electrical leads. The investigated nanopillars have either circular (diameter $d \approx 40$ nm) or elliptical (50×100 nm²) cross-sections. The device is connected to microwave probes and a dc current flows through a bias-tee, along with a 100 μ A ac current. The high frequency components of the resistance changes due to magnetization dynamics are analyzed using a spectrum analyzer with a bandwidth of the circuit of $0.1 \leq f \leq 20$ GHz. The electron flow from the thick to the thin Cu layer lead, known to cause a destabilizing or switching torque, is defined as the negative current polarity. All measurements are performed at RT and for each power spectrum $\Delta P(I, H)$ presented the current independent background noise has been subtracted.

The anisotropic magnetoresistance (AMR) of a single magnetic layer nanopillar at almost zero dc bias (0.1 mA) and a magnetic field oriented perpendicular to the sample plane (ptp) is shown in Fig. 1(b). Starting from $H = 0$ in a low resistance state dV/dI saturates in a high resistance state at magnetic fields above 5 kOe, indicating a ptp magnetization alignment, parallel to H . This field is reduced from the out-of-plane demagnetization field of Co for the unpatterned film, because of the Co layer confined in the nanopillar yielding an out-of-plane demagnetization factor of 6.72 in cgs units (compared to 4π of the unpatterned film). This was calculated from 6-fold integration of dipole-dipole interaction for the given geometry

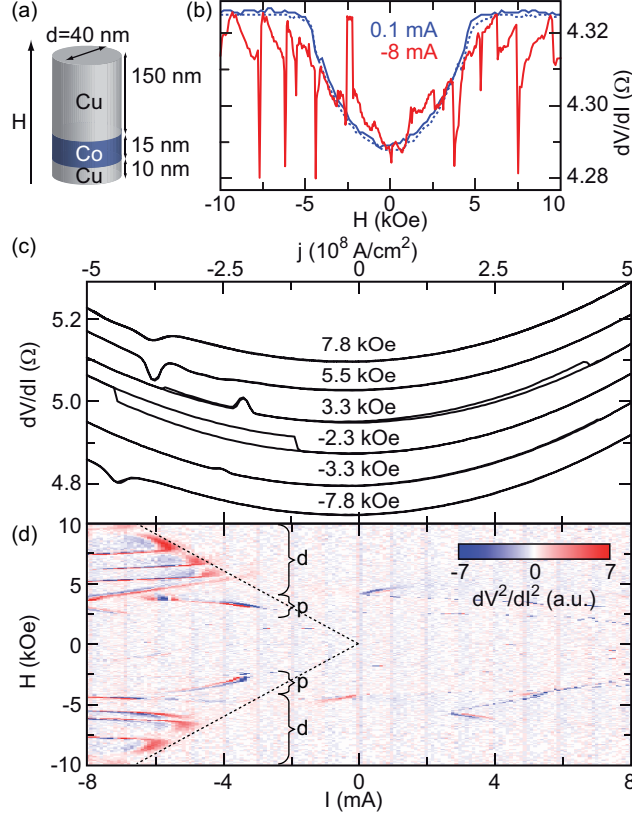


FIG. 1: (color online) (a) Schematic of a circular single Co-layer nanopillar with asymmetric Cu leads. (b) dV/dI vs H at $I = 0.1$ mA (backward field-sweep direction is marked by dotted line) and at -8 mA (the increased resistance due to the increased current has been subtracted). (c) dV/dI vs I for representative H values. (d) False color plot of d^2V/dI^2 vs I for $|H| \leq 10$ kOe. The black dashed line indicates the boundary of the resistance features; p and d denote the peak and dip regimes in dV/dI in (c), respectively.

[21]. For high negative current values of $I = -8$ mA ($j \approx -5 \times 10^8$ A/cm²) there are resistance anomalies superimposed on this AMR curve in the form of pronounced dips and peaks, which are absent for positive current values (not shown). Typical dV/dI changes as a function of I are shown in Fig. 1 (c) for different H of both polarities. To better visualize the current and field dependence of these resistance curves and for a better distinction from the parabolic background (Fig. 1(b,c)) we plot in Fig. 1(d) the second derivative d^2V/dI^2 (color coded) as a function of I and applied ptp- H -field. For $I > 0$ no pronounced dips and peaks are observed, consistent with predictions [14]. For $I < 0$ and increasing absolute field values we first observe peaks (p) in dV/dI , which represent an increase in junction resistance.

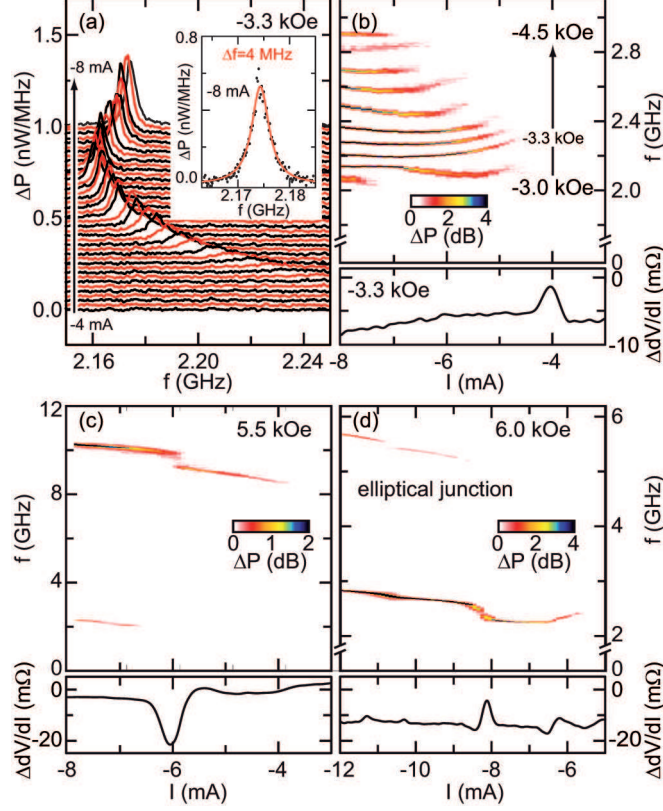


FIG. 2: (color online). Microwave power spectra $\Delta P(I, H, f)$ for circular (a)-(c) and elliptical (d) nanopillar at RT. (a) $\Delta P(f)$ for $H = -3.3$ kOe and $-8 \text{ mA} \leq I \leq -4 \text{ mA}$ (curves are shifted for clarity); inset: Lorentzian fit to the spectra taken at $I = -8 \text{ mA}$. (b) Current dependence of ΔP in logarithmic scale at different field values ($H = -3.0, -3.1, -3.3, -3.5, -3.7, -3.9, -4.0, -4.2, -4.3, -4.5$ kOe); bottom: $\Delta dV/dI$ vs I at $H = -3.3$ kOe. (c) ΔP vs I at $H = 5.5$ kOe; bottom: $\Delta dV/dI$ (parabolic background subtracted) vs I at $H = 5.5$ kOe. (d) ΔP vs I at $H = 6.0$ kOe; bottom: $\Delta dV/dI$ vs I at 6 kOe.

These features shift with increasing fields to higher negative current values. The opposite dependence is observed for the dips (d), appearing at slightly higher absolute magnetic fields. The dips indicate a decrease in junction resistance, which has been theoretically attributed to spin-wave excitations [14, 16]. As shown in Fig 1(c) there exists an asymmetry in the amplitude and current value of peaks and dips with regard to the field polarity. Hysteretic switching effects is observed in a small range near $H = -2.3$ kOe. Similar results are present in elliptically shaped nanopillars (see Fig. 3(d)), consistent with recent experimental work [12, 13].

First we consider the frequency spectrum of the circular sample for $H = -3.3$ kOe and currents from -4 mA to -8 mA (Fig. 2(a)). At $I = -4.8$ mA, slightly beyond the peak observed in $\Delta dV/dI$ (Fig. 2(b), bottom), we begin to resolve microwave emission at $f \approx 2.23$ GHz. $\Delta dV/dI$ denotes that the parabolic background has been subtracted. As the negative current is increased in magnitude the initial signal grows in amplitude and shifts to smaller frequencies until $I \approx -6.8$ mA, beyond which the excitation frequency increases again. The very narrow linewidth of 4 MHz for Co at RT (inset Fig. 2(a)) demonstrates the unexpected high coherence of the observed mode. As one can see in Fig. 2(b) the above described "low" frequency ("low- f ") mode is representative for the peak regime (compare Fig. 1(d)). The onset of microwave emission in Fig. 2(b) shifts to higher negative current values for increasing negative fields consistent with the shift of the peak position in the d^2V/dI^2 vs I diagram (Fig. 1(d)). Please note that the output power ΔP does not directly scale with the peak amplitude in the dV/dI vs I curves (Fig. 1(c)), since we observe lower microwave power at $H > 0$ (not shown) where the peak amplitudes are larger.

Besides the "low- f " mode an additional high frequency mode is observed (Fig. 2(c)). The onset of the "high- f " mode is related to a decrease in dV/dI vs I near -4 mA (bottom panel of Fig. 2(c)) and does not correspond to a higher harmonics of the "low- f " mode. The frequency of this high- f mode with a typical linewidth of ~ 10 MHz near $I = -5$ mA increases linearly with increasing negative current. The microwave signal exhibits a frequency jump near -6 mA linked to a strong dip in the differential resistance. The jump is attributed to transitions between different excited spin-wave modes as theoretically predicted [15]. The bistability of both low- f and high- f mode vanishes for further increasing fields (Fig. 3(a)). In comparison to single mode excitations the modes in the bistability regime have broader linewidths of 10 MHz and 90 MHz for the low- f and high- f mode, respectively, at $I = -8$ mA and $H = 5.5$ kOe. This indicates a decrease in temporal coherence [22]. $\Delta dV/dI$ of nanopillars with elliptical cross-section in Fig. 2(d), bottom, shows alternating dips and peaks. Surprisingly, only one narrow mode together with its first harmonic is observable. The assignment to peaks and dips is not as straightforward and more complex.

To further explore the diversity of the observed modes we discuss the field dependence of the emitted microwave power for $I < 0$. For the circular sample (Fig. 3(a)) multiple mode frequencies are observed for both field polarities. Besides the low- f mode these are

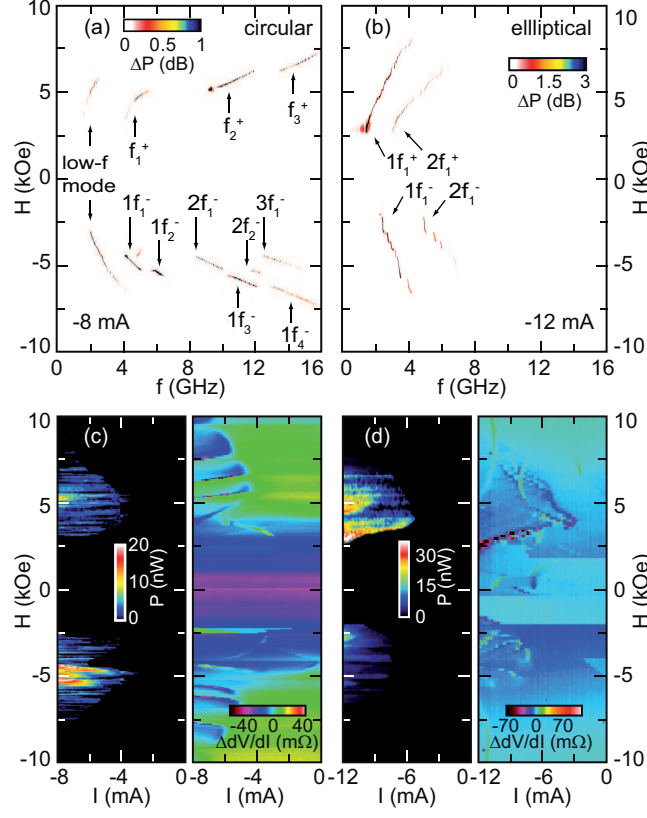


FIG. 3: (color online). (a) Emitted microwave power ΔP of the circular nanopillar as a function of out-of-plane magnetic field at $I = -8$ mA. (b) Field dependence of ΔP of the elliptical nanopillar at $I = -12$ mA. (c) Circular nanopillar, left panel: Integrated microwave power in false color plot vs I and H ; right panel: false color plot of the differential resistance $\Delta dV/dI$ (parabolic background subtracted) vs I and H . (d) Same as in (c) for the elliptical nanopillar.

the high- f modes f_i^+ , $i = 1, 2, 3, \dots$, for $H > 0$ and f_i^- for $H < 0$ together with their higher harmonics $n \cdot f_i^-$, $n = 1, 2, 3, \dots$. For a given mode the frequency corresponds to an eigenmode of the Co nanodisc and increases nearly linearly with the applied field as expected from the theoretical models [16, 19]. A field asymmetry concerns the measured frequencies f_i^+ and f_i^- , which show also jumps.

For the elliptically shaped nanopillar the field dependence of the mode frequencies is less complex, because only one mode together with its first harmonic is excited (Fig. 3(b)). Again a strong asymmetry appears concerning the field polarity, since $n \cdot f^+(H) \neq n \cdot f^-(H)$ and frequency jumps appear for negative fields only. Hence the asymmetry in the transport measurements ($\Delta dV/dI$ vs I in Fig. 3(d), right panel) reflects that of the observed frequency

behavior as well as that of the integrated microwave power (Fig. 3 (d), left panel). The correlation of the resistance changes (Fig. 3 (c,d), right panels) to the microwave power output (Fig. 3 (c,d), left panels) is clearly visible, but there is still a lack in understanding the link to the quantitative magnitude of the power.

Micromagnetic calculations of excited normal modes for circular and elliptical nanoelements exhibit low frequency uniform precession modes and higher frequency modes of different (even/odd) symmetries [19]. For elliptical shapes the many symmetry modes are merging into fewer ones as calculated from spin-wave dispersion for discrete wave vectors. This may explain the fewer high frequency modes of elliptical compared to circular elements (Fig. 3a,b), besides the lower elliptical symmetry. A more rigorous treatment has to analyze for the lowest critical current of modes being driven unstable. Quantitative predictions have failed so far because of the difficulty in combining spin diffusion with micromagnetic simulations. It has been argued that inhomogeneities in the magnetization transverse to the current flow direction reduce the resistance of a single magnetic layer due to a mixing of spin channels. As the high- f mode of circular pillars is linked to the dips in the differential resistance one could attribute this mode to transverse spin waves, which are expected in single magnetic layer nanopillar devices [14, 16]. In order to compare our measurements for the circular nanopillar with calculated eigenfrequencies of a circular Co nanoelement [19], we extrapolate the high frequency f_3^+ mode (Fig. 3(a)) to higher fields. The extrapolated value of about 40 GHz at 20 kOe agrees well with the calculated value for transverse spin waves.

The peaks in dV/dI , equivalent to an increase in junction resistance, may be explained by inhomogeneities in the magnetization normal to the thin film plane, i.e. due to a GMR-like effect. These peaks are most pronounced at relatively low fields ($H \sim 3 - 5$ kOe) for the circular pillar (Fig. 2(b)). A circular pillar with diameter of $d \approx 40$ nm and a Co thickness of 15 nm, together with the current induced Oersted field and the external ptp-H field, enables the formation of a vortex inside the FM layer [23–26]. The lowest excitation mode for a vortex is the gyroscopic precession of the core with frequencies of the order of $f \sim 1$ GHz [27], comparable to the mode frequency in Fig. 2(b). It has been shown [10] that the vortex core dynamics can be excited by spin-polarized currents. In that case micromagnetic simulations demonstrate a vortex-core precession with unequal trajectories on either side of the FM layer, resulting from inhomogeneities in the magnetization perpendicular to plane.

Therefore we suppose the low- f mode to be a vortex-core like precession. The more complex resistance changes, observed in Fig. 2(d), bottom, may give evidence that the mode near 3 GHz and its overtone originate from multivortex-state precessions [28].

In conclusion, we have observed current-induced triggering of highly coherent spin waves in single Co layer nanopillars at RT by an unpolarized current for out-of-plane magnetic fields. Dynamical modes at different frequencies are found and a possible correlation to transverse spin waves and vortex-core dynamics is discussed for circular and elliptical cross-sections of the nanopillars. These experimental data require more detailed simulations which we hope to have stimulated by this work.

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